TOSHIBA BiCD Digital Integrated Circuit Silicon Monolithic

# **TB62731FU**

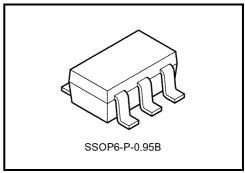
# Step-up DC-DC Converter for White LED Driver

The TB62731FU is an LED driver which uses a high power efficiency step-up DC-DC converter. The converter turns on/off from 2 to 6 white LEDs in series.

The IC incorporates an N-channel MOSFET transistor which switches a coil. Also, a function which reduces LED current depending on increase in temperature.

The mean LED current can be easily set using an external resistor.

The IC is ideal as a driver for LED light sources used as liquid crystal backlights for PDAs, cellular phones, and handy terminals.



Weight: 0.016 g (typ.)

#### **Features**

- Maximum output voltage: Vo ≤ 28 V
- Mean LED current values set according to external resistor

 $14 \text{ mA (typ.)} @R_{\text{sens}} = 2.7 \Omega$ 

 $20 \text{ mA (typ.)} @R_{\text{sens}} = 1.8 \Omega$ 

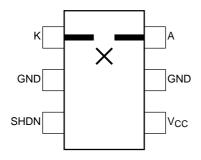
- Supply power: Up to 320 mW supported
- Compact package: SSOP6-P-0.95B, 6 pins
- Built-in temperature derating function: LED current derated automatically depending on temperature
- High power efficiency

Up to 80% of peak power efficiency achieved using recommended components

Ron =  $2.0 \Omega$  (typ.) @V<sub>IN</sub> =  $3.2 \sim 5.5 \text{ V}$ 

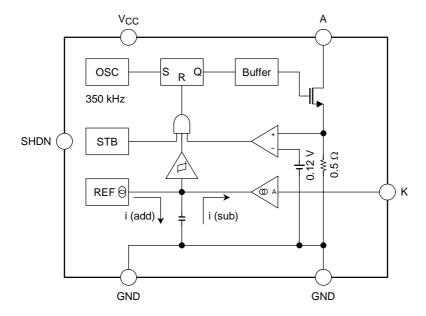
Built-in low Ron power MOS switch

## Pin assignment (top view)



# **Block Diagram**

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# **Pin Functions**

No	Symbol	Function
1	K	Pin connecting LED cathode to resistor used to set current. Feedback pin for voltage waveforms for controlling LED constant current.
2, 5	GND	Ground pin for logic
3	SHDN	IC enable pin. When Low, Standby Mode and pin A turned off.
4	V <sub>CC</sub>	Input pin for power supply for operating the IC. Operating voltage range: 3.0~5.5 V
6	А	DC-DC converter switch pin. The switch is an N-channel MOSFET transistor.

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Note: Connect both GND pins to ground.

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# Absolute Maximum Ratings (unless otherwise specified, $T_{opr} = 25$ °C)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	-0.3~+6.0	V	
Input voltage	V <sub>IN</sub>	-0.3~+V <sub>CC</sub> + 0.3	V	
Pin A (anode) current	I <sub>o</sub> (A)	+270	mA	
Pin A voltage	V <sub>o</sub> (A)	−0.3 <b>~</b> +28	V	
		0.41 (IC only)		
Power dissipation	P <sub>D</sub>	0.47 (IC mounted on PCB) (Note)	W	
Saturation thermal resistance	R <sub>th (j-a)</sub> 1	300 (IC only)	°C/W	
Saturation thermal resistance	R <sub>th (j-a)</sub> 2	260 (IC mounted on PCB)		
Operating temperature range	T <sub>opr</sub>	-40~+85	°C	
Storage temperature range	T <sub>stg</sub>	-40 <b>~</b> +150	°C	
Maximum junction temperature	Tj	125	°C	

Note: Derate power dissipation by 3.8 mW/°C from the maximum rating for every 1°C exceeding the ambient temperature of 25°C (when IC is mounted on PCB).

# Recommended Operating Conditions (unless otherwise specified, $T_{opr} = -40 \sim 85$ °C)

Characteristics	Symbol	Test circuit	Test condition	Min	Тур.	Max	Unit
Supply voltage	V <sub>CC</sub>	_	_	3.0		4.3	V
SHDN pin high-level input voltage	V <sub>IH</sub>	_	_	V <sub>CC</sub> - 0.5	_	Vcc	V
SHDN pin low-level input voltage	V <sub>IL</sub>	_	_	0	_	0.5	V
SHDN pin high-level input pulse width	tpw SHDN	_	_	500	_	_	μS
Set LED current (mean)	Io	_	$V_0$ (A) = $V_{IN}$ 3.0 V, $V_{OUT}$ 16 V	5	_	20	mA

# Electrical Characteristics (unless otherwise specified, $Ta = -40 \sim 85$ °C, $V_{CC} = 3.0 \sim 5.5$ V)

Characteristics	Symbol	Test circuit	Test condition	Min	Тур.	Max	Unit
Supply voltage	V <sub>CC</sub>	_	_	3.0	_	5.5	V
Current consumption at operation	I <sub>CC</sub> (ON)		V <sub>CC</sub> = 3.6 V	_	0.6	0.9	mA
Current consumption at standby	I <sub>CC</sub> (SHDN)		SHDN = 0 V		0.5	1.0	μΑ
SHDN pin current	I_SHDN	_	SHDN = V <sub>CC</sub> , Built-in pull-down resistor	_	4.2	7	μА
Internal MOS transistor on-resistance	Ron	_	I (A) ≦ 270 mA, Including detected resistance	_	2.0	2.5	Ω
Internal MOS transistor switching frequency	fosc	_	_	275	350	425	kHz
Pin A voltage	V <sub>o</sub> (A)		_	28	_	_	V
Pin A current	I <sub>o</sub> (A)		_	210	240	270	mA
Pin A leakage current	I <sub>oz</sub> (A)		_	_	0.5	1	μА
Set LED current (mean)	Io	_	$V_{CC} = 3.2 \sim 4.2 \text{ V},$ $R_{sens} = 1.8 \Omega$ $T_{opr} = 25^{\circ}C$ (Note 1)	17.6	20	22.4	mA
Pin K derating start ambient temperature	Tdel	_	Equivalent to R_sens = 1.8 $\Omega$ , L = 4.7 $\mu$ H, V <sub>0</sub> = 16 V	_	45 (Note 2)	_	°C

Note 1: Because the temperature derating function operates, measure when  $Ta = 25^{\circ}C$ .

Note that fluctuation in R\_sens resistors is not included in the specified value.  $I_0$  may be different from the specified value due to the relation between the inductor value and load.

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Note 2: Guaranteed by design

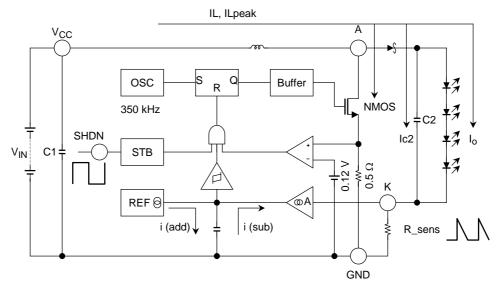


Figure 1 Application Circuit

The basic TB62731FU circuit uses a step-up DC-DC converter and burst control of current pulse.

### **Basic Operation**

The internal MOS transistor (NMOS) is turned on at  $f_{OSC} = 350$  kHz, charging energy to the inductor. Inductance current IL increases from 0. When IL = ILpeak = 240 mA (typ.) or when 5/6 (83.3%) of  $f_{OSC}$  (= 350 kHz) is reached, the transistor is turned off.

At that time, the coil maintains IL = ILpeak, the Schottky diode is turned on, and IL = Ic2 flows. Then, Ic2 decreases, reaching IL = 0.

The above operation repeats. When Ic2 is fully charged, the surplus current becomes  $I_0$ , which flows to the LED.

The graph below shows details of the basic pulse used for burst control.

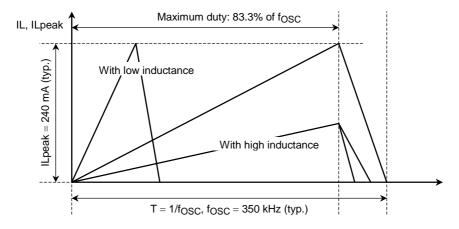


Figure 2 Switching Waveform of Inductance

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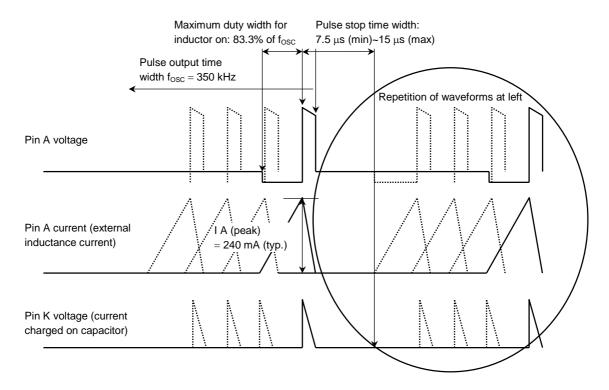


Figure 3 Burst Control Waveforms

#### **Burst Control**

Burst control is control of the number of current pulses, shown in the graph on the previous page. Control is repeated in desired cycles. The current pulse in the graph is the charged current on capacitor 2 (C2) for output.

The current pulse is supplied to the LED as current discharged from the output-side capacitor. The current pulse flows to GND via R\_sens.

The waveform of the voltage charged on the output-side capacitor is fed back to the IC from pin K via C2.

The internal circuit which uses pin K for input controls the number of current pulses so that the mean voltage value of the obtained voltage waveform is 36 mV. As a result, the output current is controlled as the constant current (= mean current).

Connecting R\_sens =  $1.8 \Omega$  obtains the mean current ( $36 \text{ mV} \div 1.8 \Omega = 20 \text{ mA}$ ).

Current is controlled by PFM (pulse frequency modulation) because the time when the output pulse is generated varies (increases/decreases).

A prerequisite is that the input power from  $V_{IN}$  is larger than the output power to the LED load. The constant current is maintained by fixing a pulse stop time of 7.5~15  $\mu$ s and increasing/decreasing the number of current pulses. When the input power is more than the output power, the number of current pulses is fewer; when less, the number of pulses is larger.

The burst frequency (pulse generation frequency) at controlled constant current is calculated as follows: fburst [Hz] = (number of current pulses x  $(1/275\sim1/350 \text{ kHz})$  + pulse stop time  $(7.5\sim15 \text{ }\mu\text{s})$  . . . formula 1

The IC is designed to supply a load power of 320 mW (min).

Generally, a step-up inductance of  $47 \mu H$  is used for optimum design for the load power of 320 mW. When the load power is small, the inductance must be small.

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Make sure the following condition for LED load between pins A and K is satisfied.

 $V_{IN}$  (V<sub>CC</sub>) < LED Vf total

Note that, regardless of control by the IC, LEDs are always on.



### **Standby Operation**

The SHDN pin is used to set normal or standby operation. When SHDN is set to Low, the operation is standby; when High, the LED is turned on. Current consumption in Standby Mode is 1  $\mu$ A (max).

### **Output-side capacitor setting**

When the output-side capacitor (C2) = 0.1  $\mu$ F, the peak current to be supplied to LEDs is expected to be the set current +5~+8 mA.

When  $C2 = 0.01 \mu F$ , the peak current is expected to be the set current  $+20\sim30$  mA. When  $C2 = 1 \mu F$ , the set current  $+2\sim3$  mA. Toshiba recommend  $C2 = 1 \mu F$  or more considering the LED max If.

The IC is used only for lighting LEDs. The IC does not finely control output current ripples, because eliminating ripples is considered unnecessary as the LED emittance is recognized as the integral amount.

### **External inductance setting**

The minimum external inductance is calculated as follows:

```
L (\mu H) = ((K \times P_0) - V_{IN} \min \times I_0) \times (1/f_{OSC} \min) \times 2 \times (1/I_{IP} \min \times I_{IP} \min) \dots \text{ formula } 2
```

The above parameters are described below:

Po: output power (power required by LED load)

 $P_0$  (W) = Vf LED × If LED + Vf schottky × If LED + R\_sens × If LED × If LED

LED forward current: If LED (mA) = Set current: I<sub>0</sub> (mA), LED forward voltage: Vf LED (V),

Schottky diode forward voltage: Vf schottky (V),

Setting resistance: R\_sens (Ω)

VIN min (V): minimum input voltage (battery voltage)

If the input voltage includes a resistance component, take the voltage drop into consideration for the minimum input voltage.

The input current IIN is roughly estimated as follows:

```
I_{IN} (mA) = VfLED × I_0 × (1/\eta) × (1/V_{IN}) . . . formula 3
```

When min  $V_{IN}$  = 3.2 (V), VfLED = 16 (V),  $I_0$  = 18 (mA), and  $\eta \ge 75$  (%), then  $I_{IN}$  = 0.12 (mA). As a result, the voltage drops by 1.2 V due to the 1- $\Omega$  DC resistance component. Because the IC's minimum  $V_{CC}$  = 3.0 V, the minimum  $V_{IN}$  is 3.12 V ( $V_{IN} \ge 3.12$  V).

I<sub>0</sub> (A): Mean current value set according to resistance R\_sens (Ω)

fosc (Hz): Switching frequency of internal MOS transistor

Specified values for fosc (kHz): 275 min, 350 typ., 475 max

Ip (A): Peak current value supplied to external inductor

Specified values for Ip (A): 230 min, 240 typ., 270 max

K: Margin of output power  $K = 1.1 \sim 1.3$ 

The ideal condition is to give 1.05 to 1.3 times the output power  $P_0$  as the input power.

The loss of the IC is assumed to be included in the margin.

If K is too large, it may not be possible for the current characteristic to be the specified value. Note that K > 1.

Substitute the following conditions in formula 2.

Supply voltage  $VIN = 3.0 \sim 4.3$  (V)

Output-side capacitor  $C2 = 1 (\mu F) \dots C2$  is ignored in the calculation.

Where it is assumed that,

VfLED = 16 (V), Vf schottky = 0.3 (V),  $R_sens = 1.8 (\Omega)$ ,  $I_0 = 20 (mA)$ , K = 1.1

VfLED: LED Vf

Vf schottky: Schottky diode Vf

R\_sens: setting resistance

 $I_0$ : set current K: margin

Thus,  $48.1~(\mu H)$  is selected when the input voltage is low, 3.0~V.

Note that the calculation does not consider fluctuations in inductance. To shib a recommend selection of an inductance of 1.2 times the calculated value.

The recommended inductance under the above conditions is L ( $\mu H$ ) = 48.1 ( $\mu H$ ) × 1.2  $\stackrel{>}{=}$  57.7 ( $\mu H$ ).

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### Selection of R\_sens

Resistance between pin K and GND R\_sens  $(\Omega)$  is used for setting output current  $I_0$ . The mean output current  $I_0$  can be set according to the resistance.

The mean current I<sub>0</sub> (mA) to be set is roughly calculated as follows:

 $I_0 (mA) = 36 (mV) \div R_sens (\Omega)$ 

For example, when  $R_sens = 1.8 (\Omega)$ ,  $I_0 = 20 (mA)$ .

Take a current error of ±10% (not including R\_sens error) into consideration.

The IC has a minimum output  $P_0 = 320$  (mA, choke coil = 47  $\mu$ H).

At that time, if the product of mean current  $I_0$  and output voltage  $V_0$  exceeds  $P_0 = 320$  (mW), mean current  $I_0$  may become less than the desired value.

If the IC is not connected to the output-side capacitor (for smoothing), set current Io can be obtained.

At that time, because the current which flows to the LED is a pulse current with a maximum peak value of 270 mA, make sure that surge current IFP (mA) does not flow to the LED.

Toshiba recommend use of components with low reactance (parasitic inductance) and minimized PCB wiring. Toshiba also recommend allocating components in the application circuit diagram as near each other as possible.

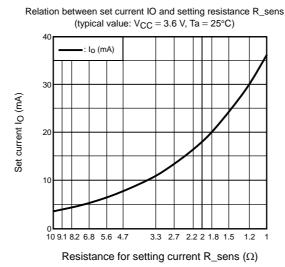


Figure 4

## **Output Derating Function**

Toshiba recommend derating LED current depending on the increase in ambient temperature.

TB62731FU is intended to safely and efficiently drive white LEDs used as backlight sources for color LCDs. The IC incorporates a function which derates current based on the set temperature (the ambient temperature when the IC is mounted), Ta.

The IC features an output current which varies according to the internally-detected temperature  $T_{js}$  as follows: when  $T_{js} = 45$  (°C), output current is 100%; when  $T_{js} = 100$  (°C), output current is 0%.

The derating start temperature  $T_s$  (°C) is determined based on Ta (Ta = Ts when the IC is not operating) by subtracting the self-generated temperature  $T_{up}$  (°C) from  $T_{js} = 45$  (°C).

$$T_s$$
 (°C) = 45 (°C) –  $T_{up}$  (°C) . . . formula 4

The derating characteristic is as shown in the graph below (Figure 5). Figure 5 shows the relation between output current change ratio and internally-detected temperature (IC temperature) T<sub>js</sub>.

The self-generated temperature  $T_{up}$  (°C) is calculated as follows:

```
T_{up} (°C) = (P loss (W) – P parts (W)) × \theta_{ja} (°C/W)) . . . formula 5
```

P loss: power loss

P parts: power loss of parts

 $\theta_{ia}$ : package saturation thermal resistance ( $\Omega$ )

The parameters are described below:

DC resistance of inductor: RDC  $(\Omega)$ 

LED forward current: If LED (A)

LED forward voltage: Vf LED (V)

Schottky diode forward voltage: Vf schottky (V)

Setting resistance: R\_sens

 $P loss (W) \simeq P_0 (W) \div \eta (\%) - P_0 (W)$ 

Po: output power

η: power efficiency

P parts (W)  $\simeq$  RDC  $\times$  I<sub>IN</sub> + Vf schottky  $\times$  If LED + R\_sens  $\times$  If LED  $\times$  If LED

 $\theta_{\rm ja}$  (°C/W)  $\leq 260$  (°C/W)

max when IC mounted on PCB

 $P_{O}(W) = V_{O}(V) \times I_{O}(A)$ 

V<sub>0</sub>: Vf LED output voltage

 $I_0$ : mean output current = set current

 $P_i(W) = V_{IN}(V) \times I_{IN}(A)$ 

P<sub>i</sub>: input power

VIN: input voltage

IIN: mean input current

$$\eta$$
 (%) = 100 × P<sub>0</sub> (W) ÷ P<sub>i</sub> (W)

Example of calculation: Where the measurement result for any lighting circuit shows the following values: RDC = 0.5 ( $\Omega$ ),  $P_0$  = 320 (mW),  $I_{IN}$  = 0.1 (mA),  $I_0$  = 20 (mA),  $R_s$ ens = 1.8 ( $\Omega$ ),  $V_f$  schottky = 0.3 (V), and  $\eta$  = 70 (%)

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The self-generated temperature  $T_{up}$  (°C) is calculated as follows:

$$T_{up} (^{\circ}C) = ((0.32 - (0.32 \times 0.7)) - (0.5 \times 0.1 + 0.3 \times 0.02 + 1.8 \times 0.02 \times 0.02)) \times 260 = 10.2 (^{\circ}C) \times 0.02 \times 0.02) \times 260 = 10.2 (^{\circ}C) \times 0.02 \times 0.02 \times 0.02) \times 260 = 10.2 (^{\circ}C) \times 0.02 \times 0.02 \times 0.02 \times 0.02) \times 260 = 10.2 (^{\circ}C) \times 0.02 \times 0.02 \times 0.02 \times 0.02) \times 260 = 10.2 (^{\circ}C) \times 0.02 \times 0.02 \times 0.02 \times 0.02) \times 260 = 10.2 (^{\circ}C) \times 0.02 \times 0.02 \times 0.02 \times 0.02 \times 0.02) \times 260 = 10.2 (^{\circ}C) \times 0.02 \times 0.02 \times 0.02 \times 0.02 \times 0.02) \times 260 = 10.2 (^{\circ}C) \times 0.02 \times 0.02 \times 0.02 \times 0.02 \times 0.02) \times 260 = 10.2 (^{\circ}C) \times 0.02 \times 0.02) \times 260 = 10.2 (^{\circ}C) \times 0.02 \times$$

Thus, the derating start temperature  $T_s$  (°C) is calculated as follows:

$$T_s$$
 (°C) = 45 (°C) – 10.4 (°C) = 34.8 (°C)

As a result,  $I_0$  is controlled in the recommended current range as shown in Figure 5.

Because saturation thermal resistance  $\theta_{ja}$  = 260 (°C/W) is the maximum value,  $\theta_{ja}$  = 210~260 (°C/W) is used as a mounting condition.

Depending on the IC characteristics, peripherals, and use environment, the derating start temperature fluctuates among ICs.

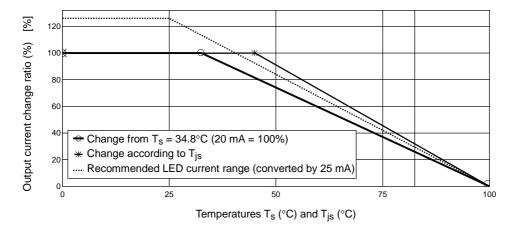
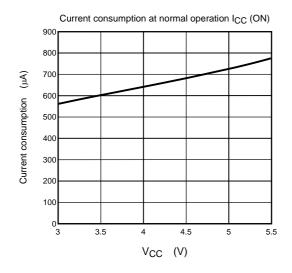
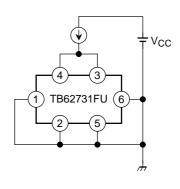
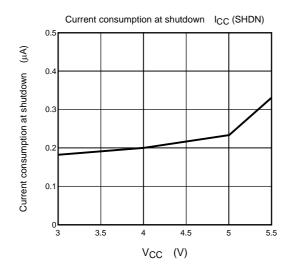


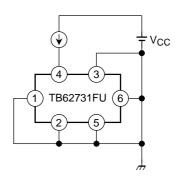
Figure 5 Derating Function of Set Current

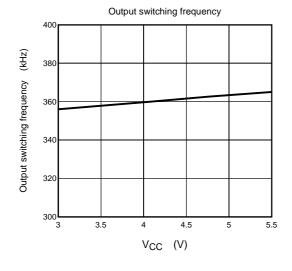
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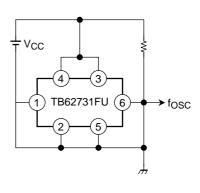






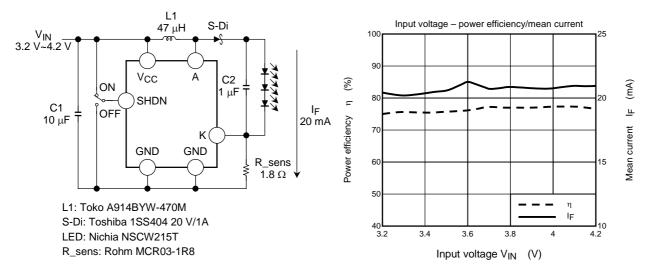


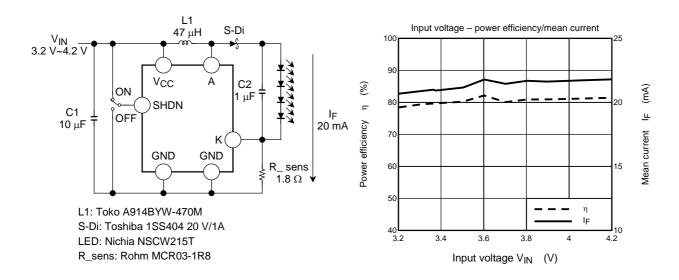


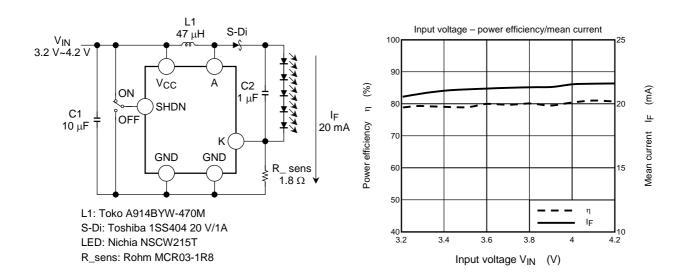


## Application Circuit Example 1 (characteristic using recommended coil as reference)

Though it is necessary to consider the DC resistance of L1, an inductance of 33 to 47 (typ.) to 68  $\mu$ H is suitable for turning on four LEDs.

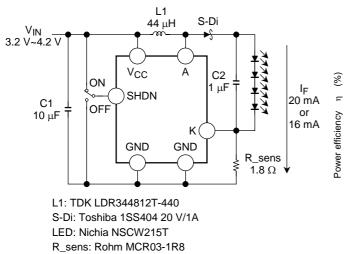


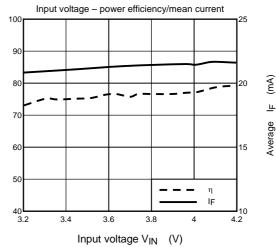


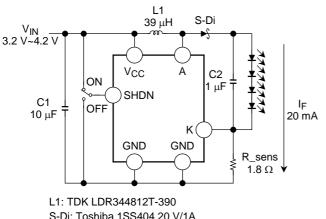


# Application Circuit Example 2 (characteristic using flat coil for handy terminal as reference)

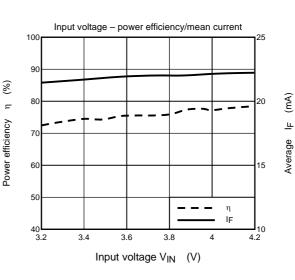
Flat coils suitable for handy terminals have a large DC resistance; thus, the power efficiency drops slightly, to about 70%.

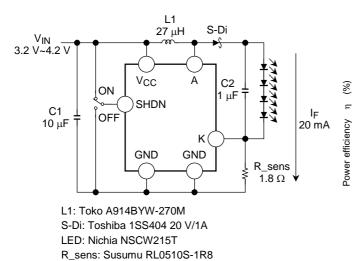






L1: TDK LDR344812T-390 S-Di: Toshiba 1SS404 20 V/1A LED: Nichia NSCW215T R\_sens: Susumu RL0510S-1R8





Input voltage – power efficiency/mean current

100

90

80

70

60

15

40

3.2

3.4

3.6

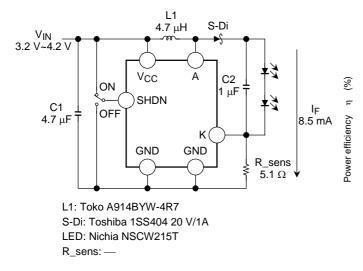
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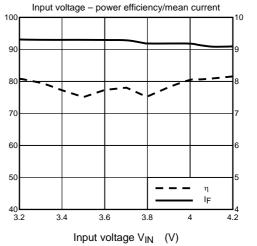
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4.2

Input voltage V<sub>IN</sub> (V)

Mean current IF (mA)



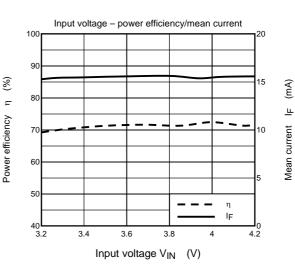


> L1: Sumitomo Special Metals CXLD (CXAD) 120-150 S-Di: Toshiba 1SS404 20 V/1A

5-Di. Toshiba 155404 20 V

LED: Nichia NSCW215T

R\_sens: --



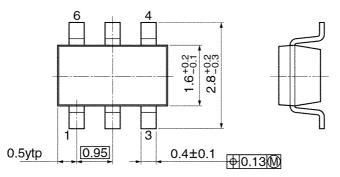
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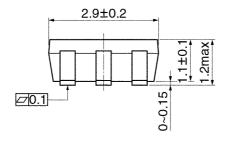
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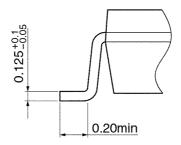


# **Package Dimensions**

SSOP6-P-0.95B Unit: mm







Weight: 0.016 g (typ.)

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## RESTRICTIONS ON PRODUCT USE

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